NSN 5962-01-100-8641

Memory Microcircuit - Page 1 of 1



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Body Length:

Between 0.825 inches and 0.835 inches

Body Width:

Between 0.245 inches and 0.255 inches

Body Height:

0.165 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-10.0/+80.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and positive outputs and w/enable and w/decoded output and dc coupled and low power

Inclosure Material:

Plastic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

11 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

350.00 nanoseconds propagation delay time, low to high level output and 350.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Ram

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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